



# Large Scale LiC6 for Electronic Applications

## Joseph A. ANDRADE\*, Jan FOLKSON, Mohamed BOUKHICHA, Amanda J. CARR, Matthew D. EISAMAN

Stony Brook University, Stony Brook, New York

\*Joseph.Andrade@stonybrook.edu

#### Introduction

While graphene exhibits extraordinary opto-electronic properties, it can be further enhanced by the introduction of lithium ions into the graphene structure. This lithiation process yields a material known as LiC<sub>6</sub>, whereby one lithium atom exists for every six carbon atoms. The addition of lithium intercalants simulates heavy n-type doping, allowing for superior electrical conductivity, while also enabling Pauli blocking to improve optical transparency.



#### **Bifacial Transfer Mechanism**

The following demonstrates a novel technique for bifacial transfer of multilayer graphene. The method involves hot-press lamination of a graphene/nickel/graphene film to polymer substrate, followed by etching of the metal substrate in a ferric chloride (FeCl<sub>3</sub>) solution for a short period of time. Due to the formation of an oxide layer between opposing graphene films, the exposed film is able to release from the remaining stack, for further transfer to a new target substrate.

### LiC<sub>6</sub> Fabrication

To facilitate lithiation, while under inert Argon atmosphere, lithium metal foil is exposed directly to the graphene sample in a small amount of lithium hexafluorophosphate (LiPF<sub>6</sub>) solution. Complete lithiation to LiC<sub>6</sub> occurs within several hours, at which point the lithium foil and remaining electrolyte are removed, followed by a rinse with diethyl carbonate (DEC).



### **Trade-off: Sheet Resistance & Optical Transmission**

There exists a trade-off between sheet resistance and optical transmittance, as they are typically inversely proportional, resulting in a material-specific "figure-of-merit" (FOM). In its natural state, graphene's FOM does not compete with industry-standard indiumtin oxide (ITO). However, due to the large increase in charge carrier density from electron-donating lithium atoms, the Fermi level of the lithiated graphene rises well above the excitation energy for optical photons, increasing its FOM substantially.





Raman spectroscopy and atomic force microscopy (AFM) measurements were performed to characterize the quality of graphene films transferred from both sides of the native nickel substrate. With regard to transfer-induced defects, the D/G ratio of each of the transferred graphene films is comparable to standard PMMA transfer.



Post-lithiation, optical transmittance and electronic conductivity of the graphene sample are both significantly improved, greatly increasing the FOM of the original graphene film. To show scalability, areas of up to 20 cm<sup>2</sup> were lithiated using the method described above, and electronic measurements demonstrate sheet resistance as low as ~2.8  $\Omega$ /sq.



LiC<sub>6</sub>



